

EXPRESS MAIL MAILING

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PATENT

Attorney Docket No.: DB000575-012

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):	Keeth, et al.)	Examiner:	Not yet assigned
Serial No.:	09/885,217)	Art Unit:	Not yet assigned
Filed:	<u>20 June 2001</u>)		
Entitled:	256 MEG DYNAMIC RANDOM ACCESS MEMORY			

SECOND PRELIMINARY AMENDMENT

Preliminary to the examination of the above-identified application, please amend that application as follows.

In the figures

Please amend FIG. 36A1 to add the reference numeral 228 and a lead line for the current I1 as shown in red in the attached copy of FIG. 36A1. The requested changes are to conform the figure to the specification, particularly page 94. No new matter has been added.

In the claims

Please add the following new claims.

Sub F1 C1

-- 466. A memory device, comprising:
an array of memory cells;
a plurality of peripheral devices for moving information into and out of said array of memory cells;
a plurality of voltage supplies for generating a plurality of supply voltages; and
a power distribution bus for delivering said plurality of supply voltages to said array and said plurality of peripheral devices, and wherein at least one of said voltage supplies comprises: